

### **General Description**

The WSF30160 is the highest performance trench N-Ch MOSFET with extreme high cell density, which provide excellent RDSON and gate charge for most of the synchronous buck converter applications.

The WSF30160 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

#### **Features**

Advanced high cell density Trench technology Super Low Gate Charge Excellent CdV/dt effect decline 100% EAS Guaranteed Green Device Available

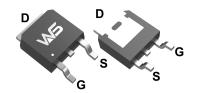
#### **Product Summery**

BVD	SS	RDSON	ID
30\	/	2.3mΩ	160A

### **Applications**

- High Frequency Point-of-Load Synchronous Buck Converter
- Networking DC-DC Power System
- Power Tool Application

# **TO-252 Pin Configuration**





### **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units
$V_{DS}$	Drain-Source Voltage	30	V
$V_{GS}$	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>C</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1,7</sup>	160	Α
I <sub>D</sub> @T <sub>C</sub> =100℃	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1,7</sup>	100	А
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	330	Α
EAS	Single Pulse Avalanche Energy <sup>3</sup>	385	mJ
I <sub>AS</sub>	Avalanche Current	72	Α
P <b></b> _@T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	92	W
T <sub>STG</sub>	Storage Temperature Range -55 to		$^{\circ}$
TJ	Operating Junction Temperature Range -55 to 175		$^{\circ}$

#### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
$R_{ heta JA}$	Thermal Resistance Junction-Ambient <sup>1</sup>		62	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case <sup>1</sup>		1.4	°C/W



# Electrical Characteristics (T<sub>J</sub>=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =250uA	30			V
$\triangle BV_{DSS}/\triangle T_{J}$	BV <sub>DSS</sub> Temperature Coefficient	Reference to 25°C , I <sub>D</sub> =1mA		0.022		V/°C
D	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =10V , I <sub>D</sub> =20A		2.3	3.0	mΩ
R <sub>DS(ON)</sub>		V <sub>GS</sub> =4.5V , I <sub>D</sub> =15A		3.8	4.6	
$V_{GS(th)}$	Gate Threshold Voltage		1.5	1.9	2.5	V
$\triangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	VGS-VDS , ID -230UA		-6.1		mV/℃
	Drain-Source Leakage Current	$V_{DS}$ =24V , $V_{GS}$ =0V , $T_J$ =25 $^{\circ}$ C			2	uA
I <sub>DSS</sub>	Drain-Source Leakage Current	$V_{DS}$ =24V , $V_{GS}$ =0V , $T_{J}$ =55 $^{\circ}$ C			10	uA
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 20 V$ , $V_{DS}$ = $0 V$			±100	nA
gfs	Forwar Trd ansconductance	V <sub>DS</sub> =5V , I <sub>D</sub> =30A		50		S
$R_g$	Gate Resistance	V <sub>DS</sub> =0V , V <sub>GS</sub> =0V , f=1MHz		0.9	1.8	Ω
$Q_g$	Total Gate Charge (4.5V)	V <sub>DS</sub> =15V , V <sub>GS</sub> =10V , I <sub>D</sub> =30A		40.3		nC
$Q_{gs}$	Gate-Source Charge			5		
$Q_gd$	Gate-Drain Charge			10.5		
$T_{d(on)}$	Turn-On Delay Time			18		
T <sub>r</sub>	Rise Time Rise Time	$V_{DD}$ =15V , $V_{GEN}$ =10V , $R_{G}$ =6 $\Omega$ ,		14		7
T <sub>d(off)</sub>	Turn-Off Delay Time	I <sub>D</sub> =1A, R <sub>L</sub> =15Ω.		46		ns
T <sub>f</sub>	Turn-Off Fall Time			19		1
Ciss	Input Capacitance	V <sub>DS</sub> =15V , V <sub>GS</sub> =0V , f=1MHz		2450		
C <sub>oss</sub>	Output Capacitance			590		pF
C <sub>rss</sub>	Reverse Transfer Capacitance			245		]

### **Guaranteed Avalanche Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
EAS	Single Pulse Avalanche Energy⁵	V <sub>DD</sub> =25V , L=0.1mH , I <sub>AS</sub> =20A	85			mJ

# **Diode Characteristics**

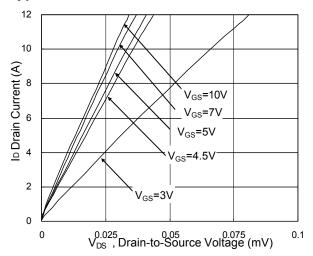
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
I <sub>S</sub>	Continuous Source Current <sup>1,6</sup>	$V_G$ = $V_D$ = $0V$ , Force Current			50	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,6</sup>				330	Α
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	$V_{GS}$ =0 $V$ , $I_{S}$ = $A$ , $T_{J}$ = $25$ $^{\circ}{\rm C}$			1.2	V

#### Note:

- 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper, t<10sec.
- 2.The data tested by pulsed , pulse width  $\leq$  300us , duty cycle  $\leq$  2%
- 3. The EAS data shows Max. rating . The test condition is  $V_{DD}$ =25V, $V_{GS}$ =10V,L=0.1mH, $I_{AS}$ =20A
- 4. The power dissipation is limited by 150°C junction temperature
- 5.The Min. value is 100% EAS tested guarantee.
- 6. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.
- 7.Package limitation current is 100A.



# **Typical Characteristics**



**Fig.1 Typical Output Characteristics** 

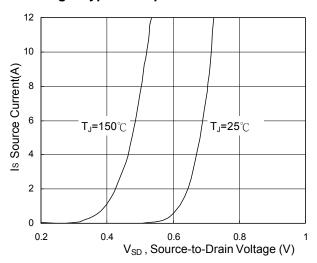


Fig.3 Forward Characteristics of Reverse

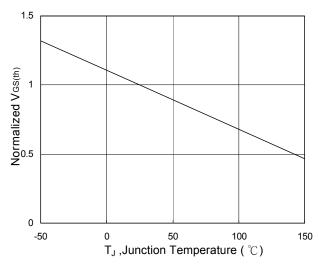


Fig.5 Normalized  $V_{GS(th)}$  v.s  $T_J$ 

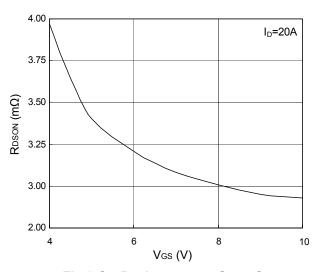


Fig.2 On-Resistance v.s Gate- Source

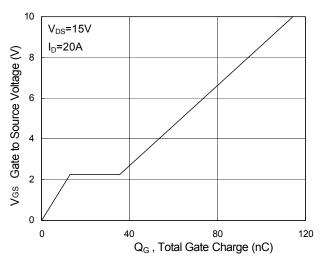


Fig.4 Gate-Charge Characteristics

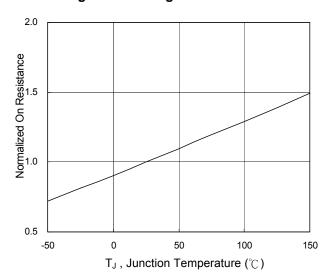
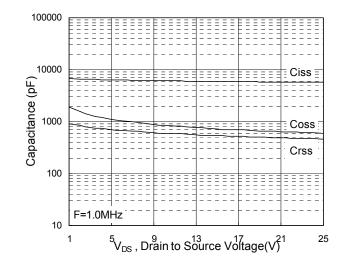


Fig.6 Normalized R<sub>DSON</sub> v.s T<sub>J</sub>





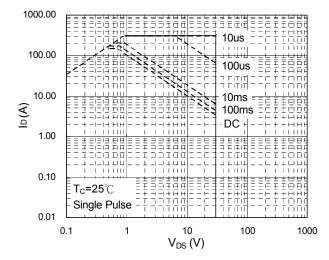


Fig.7 Capacitance

Fig.8 Safe Operating Area

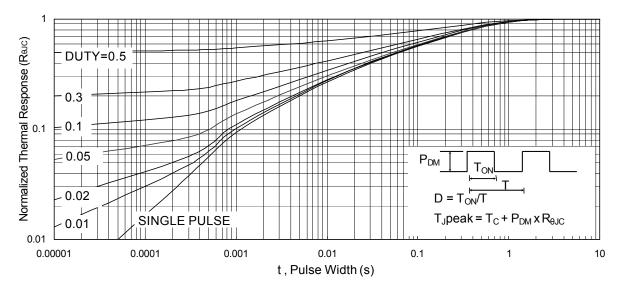


Fig.9 Normalized Maximum Transient Thermal

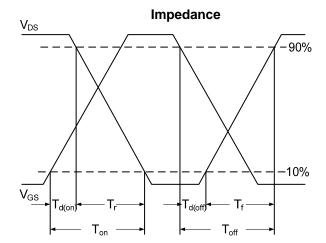


Fig.10 Switching Time Waveform

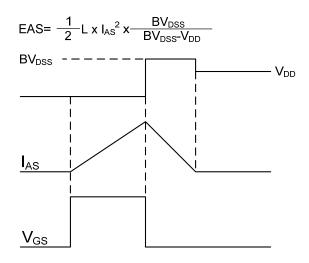


Fig.11 Unclamped Inductive Waveform



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